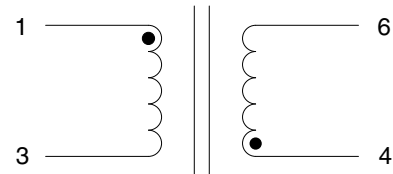
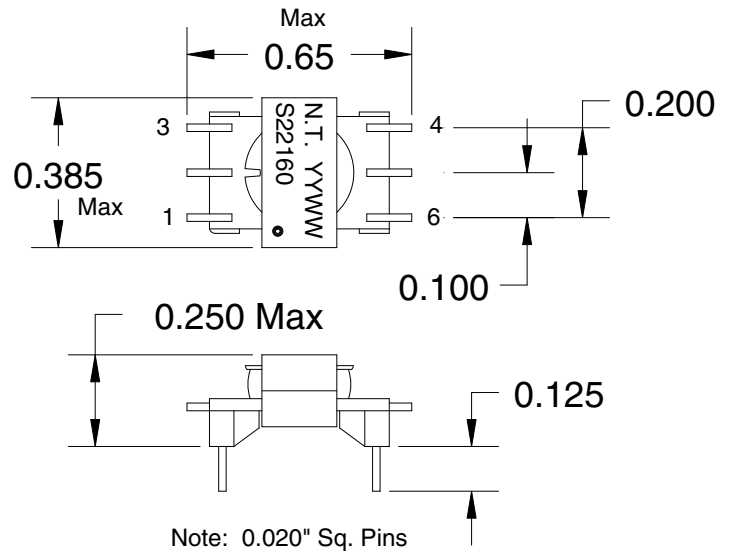


**SPECIFICATIONS:**

1. INDUCTANCE: @ 10 kHz, 0.1 Vrms,  
1 - 3 > 225 uHy
2. DCR: mOHMS MAX  
1 - 3 = 0.1  
4 - 6 = 0.1
3. LEAKAGE INDUCTANCE: 1 - 3, 0.1V @ 100kHz  
SHORT 4 - 6 < 0.5 uHy
4. INTERWINDING CAPACITANCE:  
1 - 3 to 4 - 6 @ 100 KHz, 1.0V < 15 pf
5. TURNS AND PHASE:  
1 - 3 : 4 - 6 = 1 : 1 +/- 2%
- 6 DIELECTRIC STRENGTH:  
1500 VAC 1 sec

Note: Designed to operate with Crystal Semiconductor  
CS8401.8402, 8411 & 8412



A												
REV.	DATE	ECN	BY	DESCRIPTION								
TOLERANCES ON				Newava Tech. Watertown, SD 57201 605-886-0264		Transformer Pulse, 1:1						
.XXX	.XX	ANGLE										
+ .	+ .	+ .	+ .	DATE		SCALE		MODEL		DRAWING NO.		REV.
DRAWN:										S22160		A
CHECKED: -												
APPROVED: -						NEXT ASSY:						
THIS PRINT MUST NOT BE COPIED IN WHOLE OR IN PART						OR USED DETRIMENTALLY TO OUR INTEREST				SHEET 1 OF 1		